1. INTRODUCTION

To fill the function gap of carbon film resistors, metal oxide film resistors or wirewound resistors SYNTON-TECH mages metal film resistors. The resistive element is a high contests of AL203 ceramic rod on which a thin film of Ni/Cr alloy is deposited by vacuum sputtering system. Then contact caps are pressed onto the ends of the rod and a helical grove cut through the film to give the required resistance value. Connecting copper wire are welded to the end caps. Finally the resistors are coated with multiple layers of insula- tion lacquer. **SYNTON-TECH's** MF series are suitable for all circuit applications especially tighter tolerance and low temperature coefficient are required.

2. FEATURES

- Meet American military specification MIL-R-10509F!
- Very low current noise!
- Major applications are switching power supplies, communications equipment, monoitors, testing meters.

3. EXPLANATIONS OF ORDERING CODE

DESCRIPTION : MF 1/4W 1% 100Ω

SYNTON CODE : MF 025 F 1000 T

SERIES	POWER	TOLERANCE	RESISTANCE	PACKAGE
METAL FILM FIXED RESISTOR	012 : 1/8W 025 : 1/4W 040S : 0.4W 060S : 0.6W 050 : 1/2W 100 : 1W 200 : 2W 300S : 3W 100 S : 1W small Size 200 B : 2W big Size (Please see detail of Figure1)	F : ±1% J : ±5% D : ±0.5% C : ±0.25% B : ±0.1% A : ±0.05% AA : ±0.01%	VALUE E96 Series 1% 4 Digits : 2R20 : 2.2Ω 1000 : 100Ω 1002 : 10K 1004 : 1M E24 Series 5% 3 Digits : 2R2 : 2.2Ω 101 : 100Ω 103 : 10K 105 : 1M (Please see detail of Figure6)	T=Tape Box S=Tape 26mm TR=Tape Reel B=Bulk M / MK / MB= Forming horizontal type F / FK / FKK= Forming vertical type (Please see detail of Figure4 & 5)

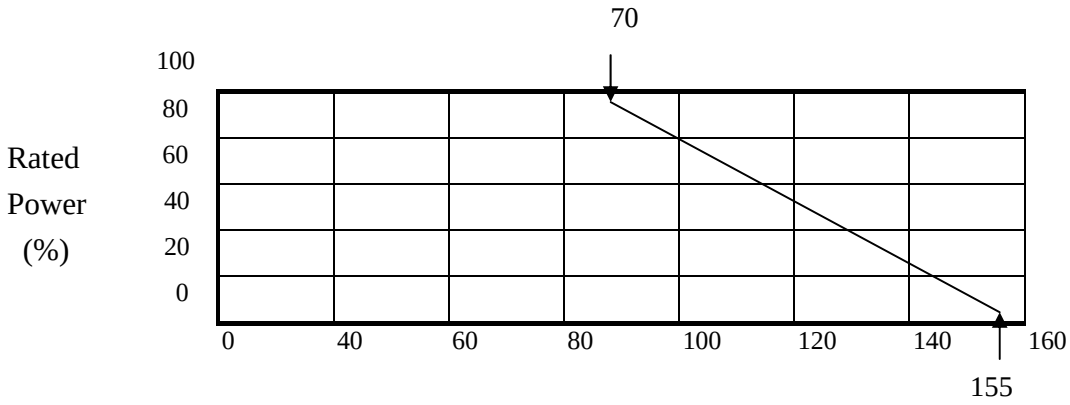
4. ELECTRICAL CHARACTERISTICS

TYPE	MF-12	MF-25S	MF-40S	MF-25	MF-50S	MF-60S	MF-50	MF-100S	MF-100	MF-200S	MF-200	MF-300S
Power Rating at 70℃	1/16W 1/8W 1/6W	1/4W	0.4W	1/4W	1/2W	0.6W	1/2W	1W	1W	2W	2W	3W
Operating Temp. Range	—55℃ ＋155℃											
Maximun Working Volt.	200V	250V	350V	250V	350V	350V	350V	500V	500V	500V	500V	500V
Maximun Overload Volt.	400V	500V	700V	500V	700V	700V	700V	1000V	1000V	1000V	1000V	1000V
Dielectric withstanding Volt.	400V	500V	700V	500V	700V	700V	700V	1000V	1000V	1000V	1000V	1000V
Value Range ±0.5%. ±1%	STANDARD 10Ω~1MΩ											
	SPECIAL Low to 0.1Ω high to 30MegΩ											
±0.25%	100Ω~100KΩ											
±0.1%	100Ω~47KΩ											
	SPECIAL VALUES AVAILABLE UPON REQUEST											
Temp. Coefficient	±10ppm/℃、±15ppm/℃、±25ppm/℃、±50ppm/℃、±100ppm/℃											

Figure 1

5. POWER RATING

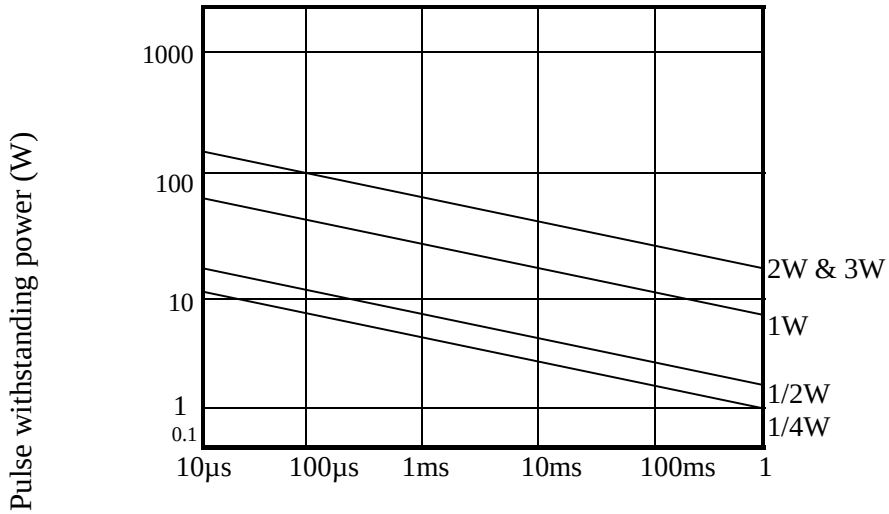
(1)Power Derating : The rated power at the temperature in excess of 70℃ shall be derated in accordance with figure2



Ambient Temperature (℃)

Figure2

(2)Pulse Loading Characteristics



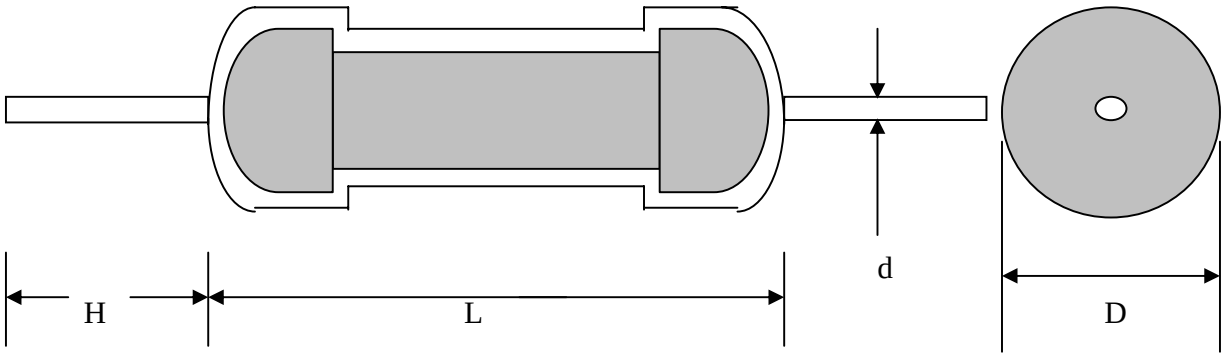
Continuous Time Of Pulse(sec.)

(2)Rated Voltage : The DC or AC(rms) continuous working voltage corresponding to the rated power is determined by the following formula:

$$E = \sqrt{R \times P}$$

Where E : Continuous rated DC or AC (rms) working voltage (v)
P : Rated power (w)
R : Resistance value (Ω)

6. DIMENSIONS

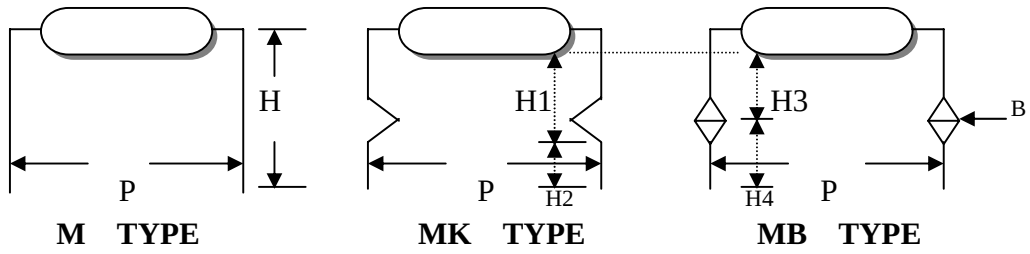


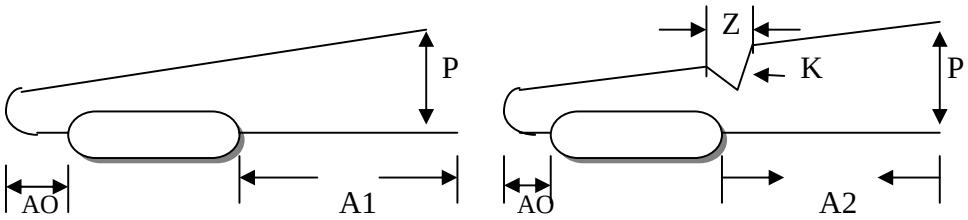
Unit: m/m

TYPE	POWER	L	D	H	d
MF-12	1/16W 1/6W 1/8W	3.5 ± 0.3	1.8 ± 0.3	25 ± 3	0.45 ± 0.05
MF-25S	1/4W				
MF-40S	0.4W				
MF-25	1/4W	6.0 ± 0.5	2.3 ± 0.3	25 ± 3	0.56 ± 0.1
MF-50S	1/2W				
MF-60S	0.6W				
MF-50	1/2W	9.0 ± 0.5	3.2 ± 0.5	25 ± 3	0.60 ± 0.1
MF-100S	1W				
MF-100	1W	11 ± 1.0	4.5 ± 0.5	35 ± 3	0.80 ± 0.1
MF-200S	2W				
MF-200	2W	15 ± 1.0	5.0 ± 0.5	35 ± 3	0.80 ± 0.1
MF-300S	3W				

Figure3

(1) FORMING PACKING





Unit : m/m

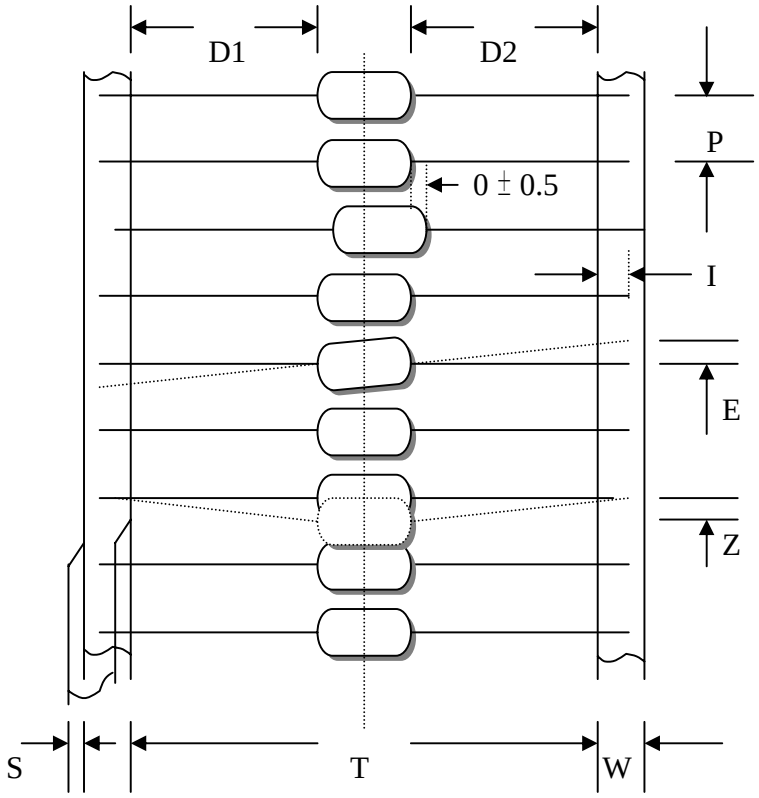
TYPE	Foming Type	P ± 1 (Min.)	H ±2.5 (Min.)	H1 ± 1 (Min.)	H2 ± 1 (Min.)	H3 ± 1 (Min.)	H4 ± 1 (Min.)	A1 ± 1 (Min.)	A2 ± 1 (Min.)	A0 ± 1 (Min.)	Remark
MF-12	M	5~	10~	—	—	—	—	—	—	—	MF-25S MF-40S
	F	—	—	—	—	—	—	25±3	—	3	
MF-25	M	10~	10~	—	—	—	—	—	—		MF-50S MF-60S
	FK	—	—	—	—	—	—	—	25±3	3	
MF-50	M	12.5~	10~	—	—	—	—	—	—	—	MF-100S
	FK	5~10	—	—	—	—	—	—	25±3	3	
MF-100	M MK.MB	15~	10~	8~	3~	8~	5~	—	—	—	MF-200S
	FK F	5~10	—	—	—	—	—	5~	5~	3	
MF-200	M MK.MB	20~	10~	8~	3~	8~	5~	—	—	—	MF-300S
	FK F	5~10	—	—	—	—	—	5~	5~	3	

Remark : 1. B = 1.15 ~ Z = 3 ±1. K = 2 ±0.5,

2. ***ALTERNATE MARKING METHOD ALSO AVAILABLE ON REQUEST.***

Figure4

(2) TAPE PACKING (T-TYPE)



Unit:m/m

TYPE	SIZE	T	P ±0.5	W ±0.5	D_1-D_2 Max.	E Max.	Z Max.	S Max.	I Min.
MF-12 MF-25S MF-40S	T-26	26±1.0	5	6	0.8	1	1.2	1	3
	T-52	52±2.0	5	6	0.8	1	1.2	1	3
MF-25 MF-50S MF-60S	T-26	26±1.0	5	6	1.0	1	1.2	1	3
	T-52	52±2.0	5	6	1.0	1	1.2	1	3
MF-50 MF-100S	T-52	52±2.0	5	6	1.2	1	1.2	1	3
MF-100 MF-200S	T-74	74±2.0	5	6	1.4	1	1.2	1	3
MF-200 MF-300S	T-74	74±2.0	10	6	1.4	1	1.2	1	3

Figure5

7. CHARACTERISTICS

(1) Insulation Resistance

Test Method : Resistors shall be clamped in the trough of a 90 degree metallic V-block, apply DC 100V between this electrode and another lead wire for 1 minute.

Acceptance Standard : 10,000 M ohm above

(2) Terminal Strength

Test Method : Pull a resistor with a weight of 1 kg for 5 seconds. Bend the terminal lead wire with 500gs weight for 90 degree and bend it for 90 degree oppositely and return to normal.

Acceptance Standard : Resistance shall not change more than ±1%. No evidence of mechanical damage.

(3) Vibration

Test Method : Total amplitude of 1.5mm. The frequency shall vary from 10 HZ to 55 HZ, for approximate 1 second. Make this test in the direction parallel to the resistor axis, and up/down for 2 hours respectively. (altogether 6 hours.)

Acceptance Standard : Resistance shall not change more than ±1%. No evidence of mechanical damage.

(4) Short Time Overload

Test Method : Resistors shall be tested 2.5 times rated voltage for 5 seconde at ambient room temperature.

Acceptance Standard : Resistance shall not change more than ±0.5%. No evidence of mechanical damage.

(5) Load Life

Test Method : Thermostatic chamber at a temperature of 70±5℃ under a rated DC voltage for 1.5 hours on and 1/2 hour off repeat this cycle for 1000±12 hours.

Acceptance Standard : Resistance shall not change more than ±1%.
No evidence of mechanical damage.

(6) Moisture Resistance

Test Method : At temperature of 40±2℃ and a relative humidity of 90-95% for 1000±12 hours, under a rating DC voltage for hours on and 1/2 hour off.

Acceptance Standard : Resistance shall not change more than ±1.5%.
No evidence of mechanical damage.

(7) Temperature Cycling

Test Method :

STEP	1	2	3	4
TEMP	-55±3℃	20±5℃	85±2℃	20±5℃
TIME	30min.	10~15min.	30min.	10~15min.

Form 1 to 4 is a cycle as shown above, repeat 5 cycles
Measure resistance after 1 hour in normal temperature.

Acceptance Standard : Resistance shall not change more than ±0.5%.
No evidence of mechanical damage.

(8) Resistance to Soldering Heat

Test Method : Immerse each terminal wire of a resistor up to 4±0.8mm away from the resistor body in the solder tank at 350±10℃ for 3±0.5 seconds.
Measure resistance in 3 hours.

Acceptance Standard : .Resistance shall not change more than ±0.5%.
No evidence of mechanical damage.

(9) Resistance to Solvent

Test Method : immerse a resistor completely in reagent at a temperature of 20~25℃for 30±5 seconds.

Acceptance Standard : No evidence of mechanical damage.

(10) Dielectric Withstanding Voltage

Test Method : Resistors shall be clamped in the trough of a 90 degree metallic V-black, apply AC between this electrode and another lead wire for 1 minute.

Acceptance Standard : Resistance shall not change more than ±1%. No evidence of mechanical damage.

(11) Solderability

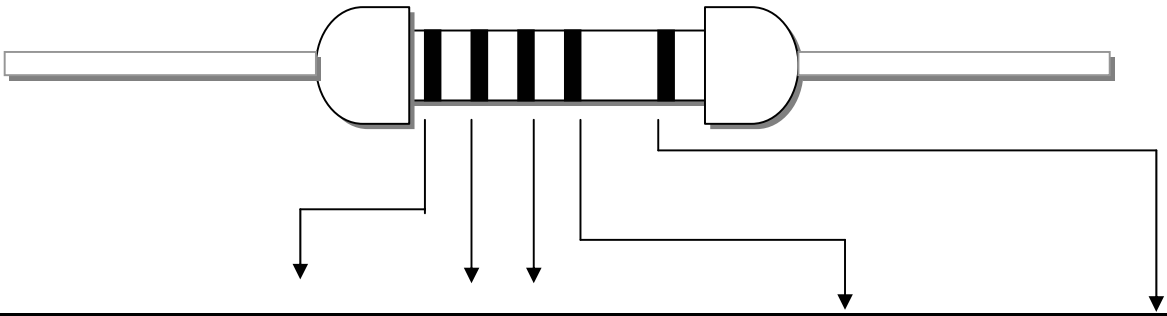
Test Method : apply flux to the terminal wire of a resistor up to 4±0.8mm away from the resistor body and immerse the flux applied portion in the solder tank at 260±5℃ for 3±0.5 seconds

Acceptance Standard : more than 95% of a circumference of the immersed portion shall be completely covered with new solder.

- **Rated continuous Working Voltage (RCWV)**

$$= \sqrt{\textbf{power rating} \times \textbf{resistance value}}$$

8. COLOR CODING



Color	1st, 2nd 3rd (Significant Figure)			(Multiplier)	(Tolerance)
Black	0	0	0	10^0	—
Brown	1	1	1	10^1	F (±1%)
Red	2	2	2	10^2	G (±2%)
Orange	3	3	3	10^3	—
Yellow	4	4	4	10^4	—
Green	5	5	5	10^5	D (±0.5%)
Blue	6	6	6	10^6	C (±0.25%)
Violet	7	7	7	10^7	B (±0.1%)
Gray	8	8	8	10^8	A (±0.05%)
White	9	9	9	10^9	AA (±0.01%)
Gold	—	—	—	10^{-1}	J (±5%)
Silver	—	—	—	10^{-2}	—

Figure6

SGS

Test Report

SYNTON-TECH CORPORATION
16F-3, NO. 79, FAR EAST WORLD CENTER SEC. 1,HSIN TAI WU ROAD, HSI-CHIH TAIPEI HSIEN, TAIWAN, R. O. C.
DONG GUAN PLANT
SHUI KOU INDUSTRIAL ZONE, DA LANG,
DNG GUAN, GUANG DONG, CHINA

Report No. : CE/2006/73556
Date : 2006/07/19
Page : 1 of 4

The following sample(s) was/were submitted and identified by/on behalf of the client as :

Sample Description	:	METAL FILM FIXED RESISTORS (EPOXY COATING)
Style/Item No	:	MF, FMF TYPE
Sample Received	:	2006/07/12
Testing Period	:	2006/07/12 TO 2006/07/19

==========

Test Result(s) : - Please see the next page(s) -

Daniel Yeh, M.R. / Operation Manager
Signed for and on behalf of
SGS TAIWAN LTD.

SGS

Test Report

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DNG GUAN, GUANG DONG, CHINA

Report No. : CE/2006/73556
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Test Result(s)

PART NAME NO.1 : MIXED ALL PARTS OF BLUE BODY

Test Item (s):	Unit	Method	MDL	Result No.1
PBBs (Polybrominated biphenyls)	---	---	---	---
Monobromobiphenyl	%	With reference to USEPA3540C. Analysis was performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and 76/769/EEC)	0.0005	N.D.
Dibromobiphenyl	%		0.0005	N.D.
Tribromobiphenyl	%		0.0005	N.D.
Tetrabromobiphenyl	%		0.0005	N.D.
Pentabromobiphenyl	%		0.0005	N.D.
Hexabromobiphenyl	%		0.0005	N.D.
Heptabromobiphenyl	%		0.0005	N.D.
Octabromobiphenyl	%		0.0005	N.D.
Nonabromobiphenyl	%		0.0005	N.D.
Decabromobiphenyl	%		0.0005	N.D.
Total PBBs (Polybrominated biphenyls)/Sum of above	%		-	N.D.
PBBEs(PBDEs) (Polybrominated biphenyl ethers)	---	---	---	---
Monobromobiphenyl ether	%	With reference to USEPA3540C. Analysis was performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and 76/769/EEC)	0.0005	N.D.
Dibromobiphenyl ether	%		0.0005	N.D.
Tribromobiphenyl ether	%		0.0005	N.D.
Tetrabromobiphenyl ether	%		0.0005	N.D.
Pentabromobiphenyl ether	%		0.0005	N.D.
Hexabromobiphenyl ether	%		0.0005	N.D.
Heptabromobiphenyl ether	%		0.0005	N.D.
Octabromobiphenyl ether	%		0.0005	N.D.
Nonabromobiphenyl ether	%		0.0005	N.D.
Decabromobiphenyl ether	%		0.0005	N.D.
Total PBBEs(PBDEs) (Polybrominated biphenyl ethers)/Sum of above	%		-	N.D.
Total of Mono to Nona-brominated biphenyl ether. (Note 4)	%		-	N.D.

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Test Report

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Test Item (s):	Unit	Method	MDL	Result
				No.1
Chromium VI (Cr+6)	ppm	UV-VIS(US EPA 7196A) after reference to US EPA 3060A.	2	N.D.
Cadmium (Cd)	ppm	ICP-AES after reference to US EPA 3052 or other acid digestion.	2	N.D.
Mercury (Hg)	ppm	ICP-AES after reference to US EPA 3052 or other acid digestion.	2	N.D.
Lead (Pb)	ppm	ICP-AES after reference to US EPA 3052 or other acid digestion.	2	N.D.

NOTE: (1) N.D. = Not Detected (<MDL)
(2) ppm = mg/kg
(3) MDL = Method Detection Limit
(4) Decabromobiphenyl ether (DecaBDE) in polymeric applications is exempted by Commission Decision of 13 Oct 2005 amending Directive 2002/95/EC notified under document 2005/717/EC.
(5) PBBEs=PBDEs=Polybrominated Diphenyl Ethers=PBDOs=PBBOs.
(6) " - " = Not Regulation
(7) " --- " = Not Applicable

SGS

Test Report

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** End of Report **